Matthew J Davies

List of Publications by Year in descending order

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		1684188	1588992	
8	58	5	8	
papers	citations	h-index	g-index	
8	8	8	136	
all docs	docs citations	times ranked	citing authors	

#	Article	lF	CITATIONS
1	A study of the inclusion of prelayers in InGaN/GaN single―and multipleâ€quantumâ€well structures. Physica Status Solidi (B): Basic Research, 2015, 252, 866-872.	1.5	16
2	Effects of an InGaN prelayer on the properties of InGaN/GaN quantum well structures. Physica Status Solidi C: Current Topics in Solid State Physics, 2014, 11, 710-713.	0.8	10
3	The effects of varying threading dislocation density on the optical properties of InGaN/GaN quantum wells. Physica Status Solidi C: Current Topics in Solid State Physics, 2014, 11, 750-753.	0.8	10
4	Room temperature PL efficiency of InGaN/GaN quantum well structures with prelayers as a function of number of quantum wells. Physica Status Solidi C: Current Topics in Solid State Physics, 2016, 13, 248-251.	0.8	7
5	Carrier distributions in InGaN/GaN lightâ€emitting diodes. Physica Status Solidi (B): Basic Research, 2015, 252, 890-894.	1.5	6
6	A study of the optical and polarisation properties of InGaN/GaN multiple quantum wells grown on a-plane and m-plane GaN substrates. Science and Technology of Advanced Materials, 2016, 17, 736-743.	6.1	5
7	Dynamics of carrier redistribution processes in InGaN/GaN quantum well structures. Physica Status Solidi C: Current Topics in Solid State Physics, 2014, 11, 738-741.	0.8	2
8	High excitation density recombination dynamics in InGaN/GaN quantum well structures in the droop regime. Physica Status Solidi C: Current Topics in Solid State Physics, 2014, 11, 694-697.	0.8	2